

Electron Microscope Pixel Array Detector (EMPAD)

High dynamic range direct electron detector for 4D STEM application

Direct electron detector solution for high dynamic range diffractive mapping at any high tension.

A superior solution

The classical process of scanning transmission electron microscopy (STEM) imaging records the scattered electron intensities by integration of fixed ring or disk detectors that may or may not be segmented. Only structural information via the dark or bright field images is obtained, and the full annular distribution is not resolved. The Thermo Scientific™ EMPAD Detector¹ samples the diffraction plane with 128x128 pixels in each STEM image point, thereby enabling detailed access to additional information on strain, orientation, electric or magnetic fields (center of mass analysis). It even potentially allows for resolution enhancement via Ptychography methods. Once data is acquired, contrast can be optimized by utilizing the full diffraction pattern or by applying masks to provide quantitative information on materials properties.

High dynamic range mapping

Typical diffraction patterns contain some intensities that are very high and uneven in their overall distribution, which determines the need for a fast high dynamic range sensor to suit mapping applications. The EMPAD Detector design provides the unique ability to record 2 pA/pixel at 200 kV with 1100 fps to record fast, high-quality diffraction patterns for ultimate results in 4D STEM, from high to low convergence and collection angle applications (nano- or microbeam methods).

Key benefits

Highest dynamic range of 1 to 1 million primary electrons per pixel / per readout to retrieve low-signal dark field and high-signal bright field information with a large field of view of 19.2x19.2 mm and the highest DQE, MTF, dynamic range and speed.

Ptychography methods allowing resolution improvements beyond the diffraction limit of optical lenses.

High tension flexibility for operation from 30–300 keV to optimize the voltage to match the diffraction application's needs or the stability needs of the materials examined.

Highest current per pixel of up to 2 pA/pixel at 200 kV in combination with 1100 fps readout speed. The high dwell capacity per pixel provides flexibility in convergence and collection angle setup to optimize the diffractive imaging result for different applications.

Easy workflow of operation from simple control of the beam current via an additional measurement unit to optimization of the result via "live view" during recording to storage of calibrated images and diffraction patterns for quantitative data analysis.

One-stop solution for assured performance. Optimum integration on Talos/Spectra TEM platforms without loss of performance on dedicated mounting port.

Large data set handling with additional 4TB of storage capacity

Integration and documentation of experiments

The EMPAD Detector is retractable, with the insertion/retraction, beam scan, and diffraction pattern recording are controlled via a dedicated software interface. Four different user-defined masks can be applied to the data during operation to obtain vital live feedback on the quality of the incoming data. All the information is obtained in one scan and, therefore, perfectly correlated. Both the diffraction pattern and the scanned area are calibrated to allow for quantitative data analysis.

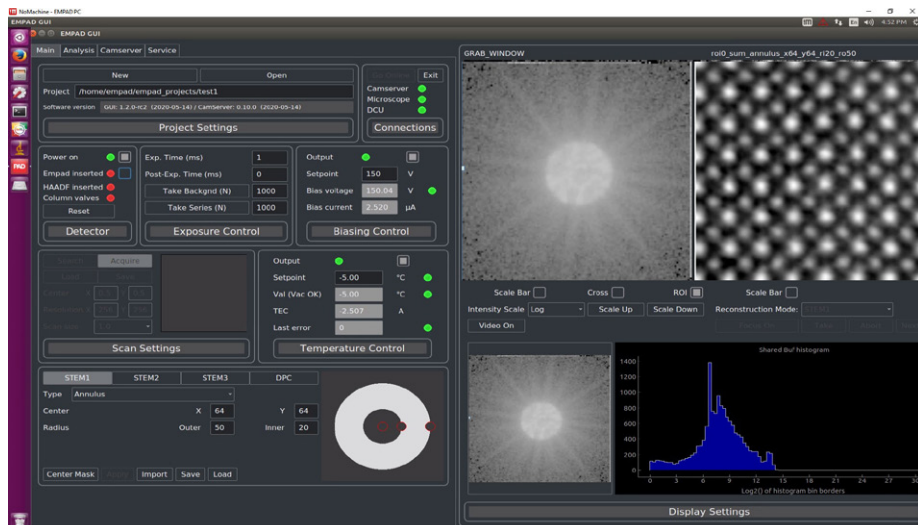


Figure 1. Screenshot of graphical user interface.

High-tension, flexible, robust design

The EMPAD Detector is radiation hard up to 300 keV and can be operated as low as 30 kV. The included current measurement unit enables the electron dose conditions on the sensor to be verified and enables easy optimization of the beam currents for the experiment at hand.

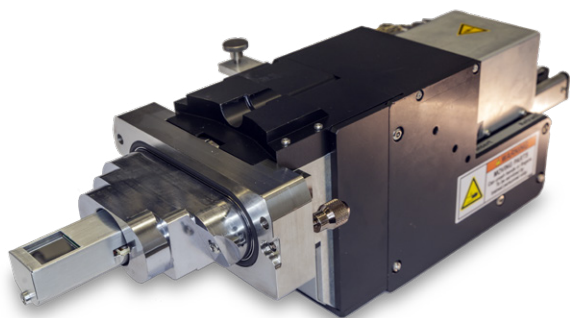


Figure 2: Image of the EMPAD including housing, retraction mechanism and sensor unit.

Integration with Thermo Scientific TEM platforms

The EMPAD Detector works with guaranteed performance on Thermo Scientific TEM platforms. The EMPAD Detector is an additional component that is compatible with all other available cameras on the Spectra and Talos platform.

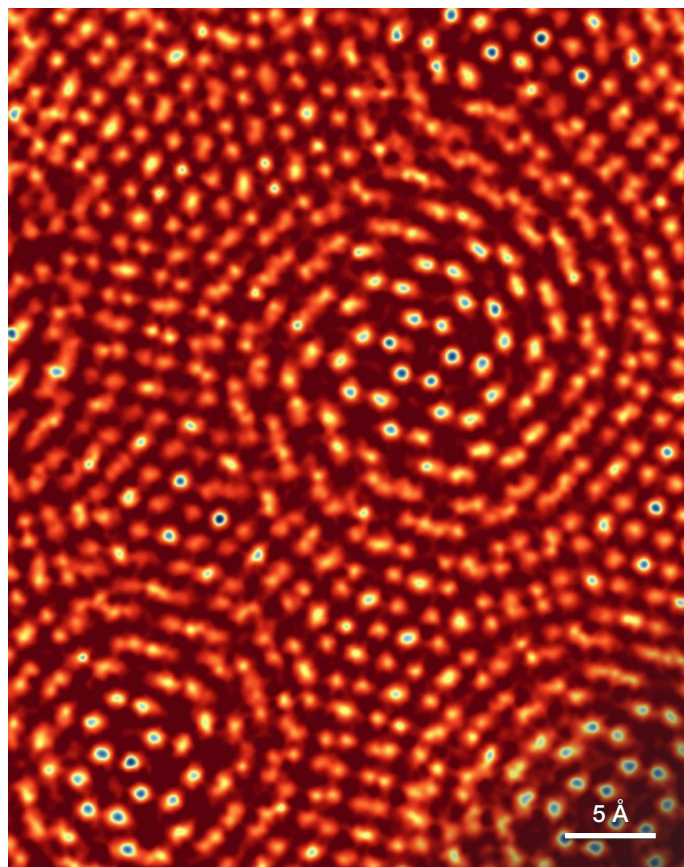


Figure 3: Super-resolution Imaging down to 39 pm by Electron Ptychography of a Twisted Bilayer of Molybdenum Disulfide recorded with an EMPAD on Titan Themis at 80 kV. Image courtesy Zhen Chen and David Muller, Cornell University².

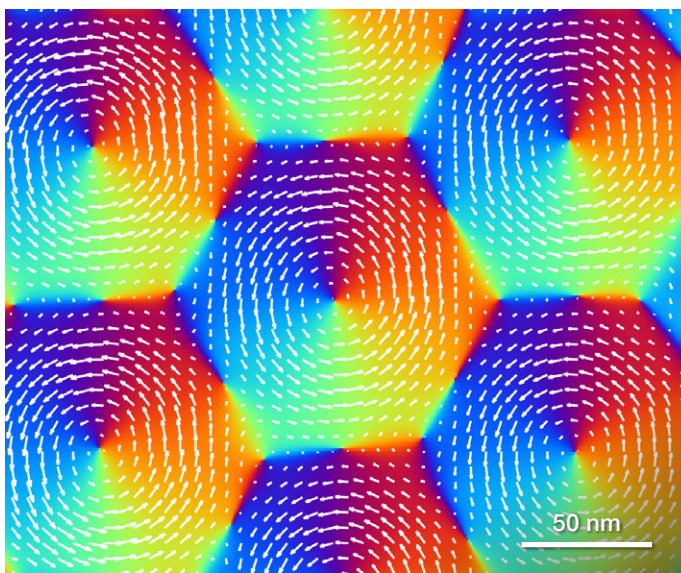


Figure 4: Lorentz Ptychography of Magnetic Skyrmions in FeGe at 100K recorded with EMPAD on Titan Themis at 300 kV. Image courtesy Zhen Chen and David Muller, Cornell University³.

EMPAD detector specifications		
Sensor dimensions	Active area	19.2x19.2 mm
	Pixels	128x128
	Pixel size	150 μm x150 μm
	Active thickness	500 μm
Performance	DQE(0):	0.96@60 keV, 0.95@80 keV and 0.94@300 keV
	Dynamic range	10 ⁶ :1 @200 keV
	Well capacity	2 pA/pixel @ 200 keV
	SNR	140 @200 keV
	Minimum integration time	30 μs
	High-tension range	30-300 keV
Maximum speed	1100 fps (128x128 pixel)	
Radiation hardness	@300 kV > 10 ¹² e/pixel	
Storage capacity	4TB SATA 7200rps HDD	
Control and imaging software	<ul style="list-style-type: none"> • Scan control for field of view and dwell time • Live synthesized STEM image via online data processing of user-defined masks for ABF, BF, DF, HAADF, iCOM and DPCx, DPCy • Live single (or series) diffraction patterns • Supportive live view annotations to set up and reproduce experiments quickly • Advanced data management to keep track of experimental metadata • Save raw data and live analysis of results • Offline analysis of projects on your laptop 	
System requirements	Talos/Spectra with Windows® 10	
Retrofit	For retrofits on your tool contact sales and service organization in your region	

